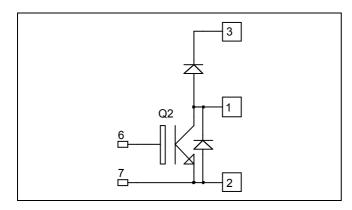


Boost chopper NPT IGBT Power Module

$$V_{CES} = 600V$$

 $I_{C} = 330A$ @ $T_{C} = 80^{\circ}C$



Application

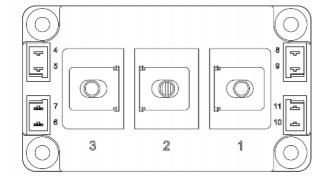
- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

Features

- Non Punch Through (NPT) FAST IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	520	
	Continuous Conector Current	$T_C = 80$ °C	330	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	800	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_C = 25$ °C	1560	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	800A @ 520V	

TAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				500	μΑ
V _{CE(sat)}	Collector Emitter saturation Voltage	, GE 10 ,	$T_j = 25$ °C		1.95	2.45	V
			$T_j = 125$ °C		2.2		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_{C} = 7.5 \text{ mA}$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				1200	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V ; V_{CE} = 25V$		18		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		1.6		111
Q_{G}	Gate charge	V_{GE} =15V, I_{C} =400A V_{CE} =300V		1.3		μС
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)		150		ns
T _r	Rise Time	$V_{GE} = \pm 15V$		72		
T _{d(off)}	Turn-off Delay Time	$V_{\text{Bus}} = 300V$ $I_{\text{C}} = 400A$		530		
T_{f}	Fall Time	$R_G = 8\Omega$		40		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C	()	160		na
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$		75		
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 300V$ $I_C = 400A$		550		ns
$T_{\rm f}$	Fall Time	$R_G = 8\Omega$		50		
Eon	Turn on Energy	$V_{GE} = \pm 15V \ V_{Bus} = 300V$ $T_j = 125^{\circ}$	С	18		mJ
E_{off}	Turn off Energy	$ \begin{array}{c} I_C = 400A \\ R_G = 8\Omega \end{array} \qquad T_j = 125^{\circ} $	С	17		1113
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 360V$ $t_p \le 10 \mu s$; $T_j = 125 ^{\circ} C$		1800		A

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RRM}	Maximum Reverse Leakage Current	$V_R = 600V$	$T_i = 25^{\circ}C$			750	μΑ
I_{F}	DC Forward Current		$T_{j} = 125^{\circ}C$ $Tc = 80^{\circ}C$		400	1000	A
V	Diode Forward Voltage	$I_F = 400A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.25	1.6	V
V_{F}			$T_i = 125^{\circ}C$		1.2		
+	Davanaa Daaayany Timaa		$T_j = 25^{\circ}C$		150		
t_{rr}	Reverse Recovery Time	T 400 4	$T_j = 125$ °C		250		ns
0	Davanga Dagayami Changa	$I_F = 400A$ $V_R = 300V$	$T_i = 25^{\circ}C$		27		C
Q_{rr}	Reverse Recovery Charge	$V_R = 300 V$ di/dt =4400A/µs	$T_j = 125$ °C		44		μC
E _{rr}	Р Р Г	αι/αι 1100/1/μ3	$T_i = 25^{\circ}C$		5.6		ma T
	Reverse Recovery Energy		$T_{i} = 125^{\circ}C$		9.2		mJ

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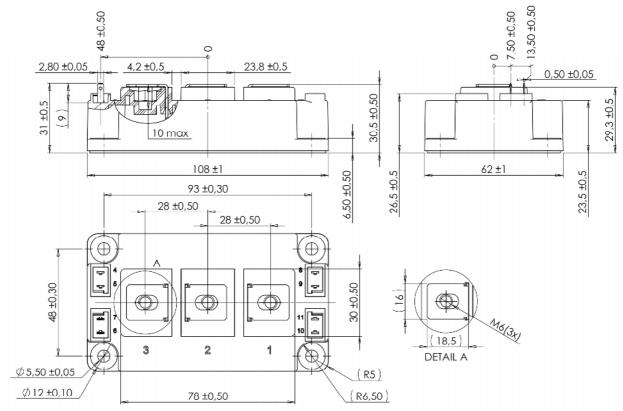
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Thermal and package characteristics

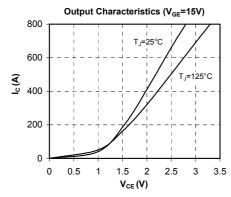
Symbol	Characteristic			Min	Тур	Max	Unit		
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.08	°C/W		
KthJC			Diode			0.15	C/ W		
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V		
T_{J}	Operating junction temperature range			-40		150			
T_{STG}	Storage Temperature Range			-40		125	°C		
$T_{\rm C}$	Operating Case Temperature			-40		125			
Torque	Mounting torque	For terminals	M6	3		5	N.m		
		To Heatsink	M6	3		5	11.111		
Wt	Package Weight					350	g		

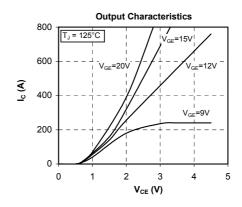
D3 Package outline (dimensions in mm)

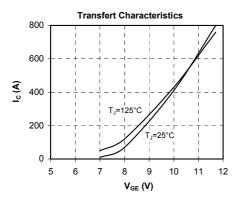


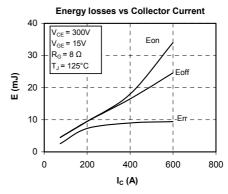


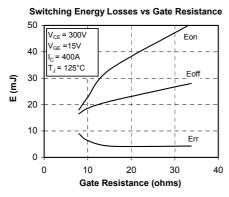
Typical Performance Curve

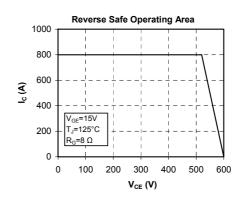


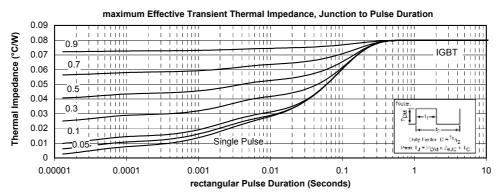






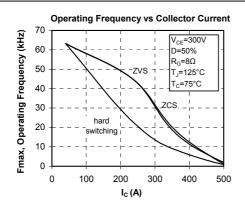


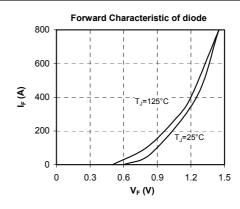


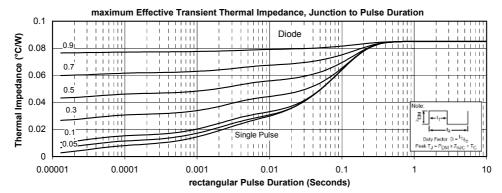


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